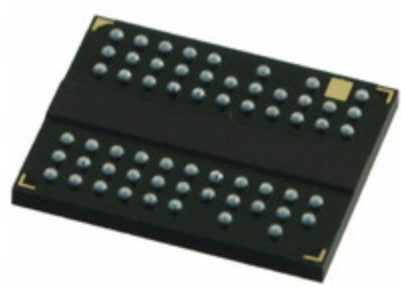


	<p>Manufacturer Part Number: MT47H64M8JN-25E IT:G</p>
	<p>Manufacturer/Brand: Micron Technology</p>
	<p>Part of Description: IC SDRAM 512MBIT 400MHZ 60FBGA</p>
	<p>Datasheets:  MT47H64M8JN-25E IT:G.pdf</p>
<p>RoHs Status:  Lead free / RoHS</p>	<p>Stock Condition: Compliant New original, 1283 pcs Stock Available.</p>
<p>Ship From: Hong Kong</p>	<p>Shipment Way: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Specifications

Part Number	MT47H64M8JN-25E IT:G
Manufacturer	Micron Technology
Description	IC SDRAM 512MBIT 400MHZ 60FBGA
Category	Integrated Circuits (ICs) > Memory
Part Status	1283 pcs Stock
Series	-
Operating Temperature	-40°C ~ 95°C (TC)
Interface	Parallel
Package / Case	60-TFBGA
Supplier Device Package	60-FBGA (8x10)
Voltage - Supply	1.7 V ~ 1.9 V
Memory Type	Volatile
Speed	400MHz
Memory Size	512Mb (64M x 8)
Memory Format	DRAM
Packaging	Bulk

MT47H64M8JN-25E IT:G is New Original in Stock, Search MT47H64M8JN-25E IT:G Datasheets, PDF, Inventory at Y-IC.com Online, Order MT47H64M8JN-25E IT:G Micron Technology with warrantied and confidence. RFQ MT47H64M8JN-25E IT:G : Info@Y-IC.com



















































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 <p>MT47H64M8CF-3:F MICRON MT47H64M8CF-3:F MICRON</p>	 <p>MT47H64M8SH-187E:H TR Micron Technology IC SDRAM 512MBIT 533MHZ 60FBGA</p>	 <p>MT47H64M8CF-3IT:F MICRON MT47H64M8CF-3IT:F MICRON</p>	 <p>MT47H64M8SH-25E AAT:H Micron Technology IC DRAM 512M PARALLEL 400MHZ</p>

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|  CP7464ATT |  FAN2512SX |  FM1100-M |  GRM155R61C225KE11J |  GRM1885C1H6R9CA01D |
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|  LMX2370SLBX |  LNBH231B |  LQG18HN47NJ00D |  MAX3491ESD+ |  MAX709RCSA-T |
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|  N1042LS120 |  NOJP106M002RWJ |  P230CH08C2K0 |  P6SMB440A-E3/52 |  PLZ27B-G3/H |
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